Electronic Version 0.0.11

Stylesheet Version: 1.0

Publication Filing Type:

new-utility

Application Type:

utility

Title of Invention:

TRANSISTOR STRUCTURE WITH THICK RECESSED SOURCE/DRAIN

STRUCTURES AND FABRICATION PROCESS OF SAME

Legal Representative:

Attorney or Agent:

Mr. Mark F. Chadurjian Esquire

Registration Number:

30739

**Customer Number Correspondence Address:** 

23123

INVENTOR(s):

Primary Citizenship:

U.S.A.

Given Name:

IU

**Andres** 

Family Name:

Bryant

**Residence City:** 

**Essex Junction** 

Residence State:

VT

Residence Country:

US

Address:

19 Wilkinson Drive

Essex Junction Vermont, 05452

Primary Citizenship:

U.S.A.

Given Name:

Mark

Middle Name:

D.

Family Name:

Jaffe

Residence City:

Shelburne

Residence State:

VT

**Residence Country:** 

US

Address:

447 Governors Lane

Shelburne Vermont, 05482

APP ID=09682957

Page 1 of 2

APP\_ID=09682957